0	Specification	Specification Symbol Condition / Comment								HTS 501-40 LC2 Unit					
	Maximum Operating Voltage		V _{O(max)}		I _{off} < 40 μADC, T _{case} = 70°C					50 kVDC					
	Maximum Isolation Voltage		Vi		Between HV switch and control / GND, continuously						± 80		kVDC		
RATINGS	Max. Housing Insulation Voltage		V _{INS}	Between switch and housing surfa		•				± 100		kVDC			
	Maximum Turn-On Peak Current		I _{P(max)}	$T_{case} = t_p < 200 \ \mu s, \ duty \ cyc$							400		KVDO		
1	Waximum Fum-On Feak ouncil		iP(max)	25°C							220		ADC		
8			20 0	t _p < 10 ms, duty cycle <1%						173		7100			
				t _p < 100 ms, duty cycle <1%						110					
Ş	Maximum Continuous Load Current		Le v	T _{case} =	Standard devices					2		ADC			
MAXIMUM	IVIAAIITIUITI COHUITUOUS LOAG CUITENT		I _{L(max)}	25°C Devices with option DLC						15		ADC			
	Max. Continuous Power Dissipation		P _{d(max)}	T _{case} = Standard devices & FC							30				
	I Wax. Continuous Fower Dissipation		I d(max)	25°C Devices with option DLC						4500		Watt			
ABSOLUTE	Linear Derating			Above Standard devices & FC, forced air 4 m/s							0.38		vvali		
	Linear Derading			25°C Devices with option DLC							79.3		W/K		
	Operating Temperature Range		To	Standard devices & options CF, GCF, ILC. (Option DLC)						-4070		C°			
4	Storage Temperature Range		Ts	Switches with option ILC may require frost protection!						-4090		C°			
	Max. Permissible Magnetic Field		В	Homogeneous steady-field, surrounding the whole switch						25		mT			
	Max. Auxilliary Voltage		V _{aux}	Built-in overvoltage limiter (replaceable)						5		VDC			
ELECTRICAL CHARACTERISTICS	Permissible Operating Voltage Range		V _{aux}	Built-III OV	reivoitage iiiriite	ei (repiace	able)				0 ± 50		kVDC		
	Typical Breakdown Voltage		Vo	NOTE: \/	is a test person	notor for a	olity								
	Typical Breakdown Voltage		V br		NOTE: V_{br} is a test parameter for quality control purposes only. Not applicable in $I_{off} > 0.5 \text{mA}$						55		kVDC		
	Typical Off-State Current		l _{off}	0.8xV _O , T _{case} =2570°C, reduced		C, reduced					40		μADC		
	Typical Turn-On Resistance		R _{stat}	Each switching path		0.1 x I _{P(max)} , T _{case} =25°C				4.25					
	,			$t_p < 1\mu s$	duty cycle < 19	1.0 x I _{P(max)} , T _{case} =25°C				5.3					
				1.0 x I _{P(max)} , T _{case} =70°C							11		Ohm		
	Typical Propagation Delay Time		t _{d(on)}	Resistive	lesistive load, 0.1 x I _{P(max)} , 0.8 x V _{O(max)} , 50-50%						250		ns		
	Typical Output Pulse Jitter	ti		Impedance matched input, V _{aux} / V _{ctrl} = 5.00 VDC						3		ns			
	Typical Turn-On Rise Time		t _{r(on)}	Resistive	Resistive load, 10-90% 0.1 x Vo				(max)		34				
	.,,,			Troolotivo loda, 10 0070			$0.8 \times V_{O(max)}$, $I_L = 0.1 \times I_{p(max)}$			62					
							$0.8 \times V_{O(max)}$, $I_L = 1.0 \times I_{p(max)}$			70			ns		
	Typical Turn-Off Rise Time	e	t _{off,} t _q	Resistive	load, 10-90%		$0.1 \times V_{O(max)}$, $I_L = 0.1 \times I_{p(max)}$			30			ns		
	Typical rain on rise rine				, , , , , , , , , , , , , , , , , , , ,		0.8 x V _{O(max)} , I _L				80				
	Maximum Turn-On Time		ton(max)	No limitation			O.O.X. VO(IIIAX), IE 1.O.X. Ip(IIIAX)				∞				
	Minimum Turn-On Time		ton(min)	ton(min) can be customized. Please consult factory							250		ns		
	Maximum Turn-Off Time		t _{off(max)}	No limitation							∞				
	Minimum Turn-Off Time		t _{off(min)}	toff(min) can be customized. Please consult factory							250		ns		
	Max. Continuous Switching		f _(max)		V _{aux} = 5.00 V Standard devices without HFS option						TBD				
	Frequency		·(max)	Sw. shutdown if f _(max) is Standard devices with HFS supply							30				
				exceeded	TTT ((max) 10		+ sufficient co				70		kHz		
	Maximum Burst Frequency		f _{b(max)}	4	on HFR for >10		thin 20µs or le				500		kHz		
	Maximum Number of Pulses / Burst		N _(max)	@ f _{b(max)}	JITII B 101 - 10	puloco W	10 10 10 10 10 10 10 10 10 10 10 10 10 1	Standard			>10		Pulses		
	Waximum Number of Pulses / Burst		IN(max)					Option I-H	IFR		>100		i uises		
					Note: Option HFB requires external buffer capacitors with a voltage rating of > 630VDC and a cpacitance of 100nF per additional Option HFB						>1000				
	Coupling Capacitance		Сс	HV side against control side						<100		pF			
	Natural Capacitance		C _N	Between switch poles, @ 0.5 x V _{O(max)}						<50		pF			
	Control Voltage Range		V _{ctrl}	The V _{ctrl} has no impact on the output pulse shape.						3 10		VDC			
	Auxiliary Supply Voltage Range		Vaux	The +5 V supply is not required in the HFS mode.						5		VDC			
	Typical Auxiliary Supply Current		I _{aux}		$V_{\text{aux}} = 5.00 \text{ VDC}$, $T_{\text{case}} = 25^{\circ}\text{C}$. $0.01 \text{ x f}_{\text{(max)}}$				uav)		300		VDO		
	Typical Auxiliary Supply Current		iaux					@ f _(max)	idX)		800		mADC		
	Fault Signal Output				Switch will be turn off, if f>f _(max) , V _{aux} <4.75V or T _{cas}				Н	=4V, L=0.5V		VDC			
	Tault Signal Output			Fault condition is indicated by a logical "L"					• • • • • • • • • • • • • • • • • • • •	11, 2 0.01		100			
	Opt. HFS, Ext. Supply Voltage V1		V _{HFS(V1)}	Stability ±3%, current consumption <0.4 mA/kHz @ 25°C							15		VDC		
	Opt. HFS, Ext. Supply Voltage V2		V _{HFS(V2)}	Stability ±3%, current consumption <0.9 mA/kHz @ 25°C						TDB		VDC			
	Intrinsic Diode Forward Voltage		V _F	$T_{case} = 25$ °C, $I_F = 0.3 \times I_{P(max)}$				- W 20 0			< 70		VDC		
	Diode Reverse Recovery Time		trrc	$T_{case} = 25^{\circ}C$, $I_F = 0.3 \times I_{P(max)}$, $di/dt = 100 \text{ A/J}$							< 250		ns		
	Dimensions		LxWxH		case = 25°C, IF = 0.3 X IP(max), 01/0t = 100 A/µs Standard housing						372x150x58		113		
(5)	Difficitions		LAVVAII	Devices with option CF, non-isolated cooling fins									mm ³		
Ž					with option DL(tod cooming min	'			ease contact the				
HOUSING	Moight	Weight				<u> </u>					manufactured!				
	TTOIGHT			Standard housing Devices with option CF, non-isolated cooling fins						ease contact the		n			
			Devices with option CF, non-isolated cooling his Devices with option DLC							manufactured!		g			
	Control Signal Input	v TTI oo	propartible with Schmitt-Trigger characteristics. Control voltage 2-10 V (3-5 V recommended for low jitter).												
							nd pin is internally connected with the safety earthing terminal (threaded insert) on bottom side.								
S	•		_					-							
S					out is used for rep rates up to the specified max. frequency f _(max) . Higher rep rates require option HFS.										
T					tput, short circuit proof. Indicating switch & driver over-heat, over-frequency, low auxiliary voltage. L = Fault.										
FUNCTIONS	Inhibit Signal Input Pin 5 / Green. TTL compatible, Schmitt-Trigger characteristics for the connection of experimental property and the connection of exp								•						
F	LED Indicators	GREEN: "Au	xiliary pov	ver good, s	er good, switch OFF". YELLOW: "Control signal received, switch ON". RED: "Fault condition, switch OFF"										
	Temperature Protection	A) Standard s	switches a	nd switches	d switches with option CF, GCF: Thermo trigger 75°C, response time < 60 s @ 3xPd(max), △T=25K (50 to 75°C). Separate driver										
		protection. B)	Switches v	ches with option DLC: 65°C, response time < 3 s @ 3xPd(max), Δ T=25K (40 to 65°C), coolant flow > 3I / min. Separate driver protection.											
-	HTS 501-40 LC2 Transistor Sw			ow Pass. Input filter				CCS Ceramic Cooling Surface. P _{d(max)} can be increased by the factor 2 to 3.							
715				*				Option C							
N.								Option C							
ER						xiliary supply inputs se time for shut dow		Option G Option IL		(copper). P _{d(max)} can be increased water). P _{d(max)} can be increased					
ORDERINGT						se time < 5s. NTC 1		Option D		PE/PFC). Pd(max) can be increased					
0							ONS PLEASE REF								
Cust	omized switching units are availa	ble on request. All	data and sp								Revision 14.03.2019 ©20	18 All rights res	served		